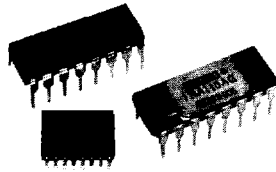


Or, Call Customer Service at 1-800-548-6132 (USA Only)



INA110

www.burr-brown.com/databook/INA110.html

Fast-Settling FET-Input INSTRUMENTATION AMPLIFIER

FEATURES

- LOW BIAS CURRENT: 50pA max
- FAST SETTLING: 4 μ s to 0.01%
- HIGH CMR: 106dB min; 90dB at 10kHz
- INTERNAL GAINS: 1, 10, 100, 200, 500
- VERY LOW GAIN DRIFT: 10 to 50ppm/ $^{\circ}$ C
- LOW OFFSET DRIFT: 2 μ V/ $^{\circ}$ C
- LOW COST
- PINOUT SIMILAR TO AD524 AND AD624

APPLICATIONS

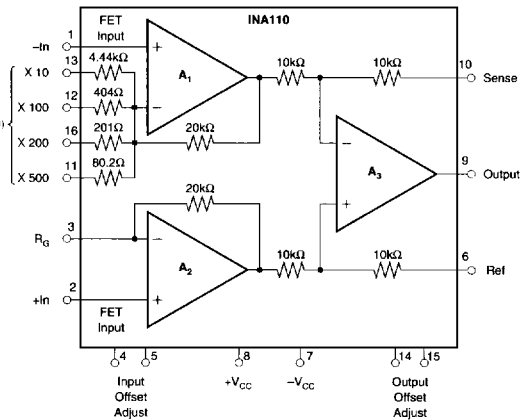
- MULTIPLEXED INPUT DATA ACQUISITION SYSTEM
- FAST DIFFERENTIAL PULSE AMPLIFIER
- HIGH SPEED GAIN BLOCK
- AMPLIFICATION OF HIGH IMPEDANCE SOURCES

DESCRIPTION

The INA110 is a versatile monolithic FET-input instrumentation amplifier. Its current-feedback circuit topology and laser trimmed input stage provide excellent dynamic performance and accuracy. The INA110 settles in 4 μ s to 0.01%, making it ideal for high speed or multiplexed-input data acquisition systems.

Internal gain-set resistors are provided for gains of 1, 10, 100, 200, and 500V/V. Inputs are protected for differential and common-mode voltages up to $\pm V_{CC}$. Its very high input impedance and low input bias current make the INA110 ideal for applications requiring input filters or input protection circuitry.

The INA110 is available in 16-pin plastic and ceramic DIPs, and in the SOL-16 surface-mount package. Military, industrial and commercial temperature range grades are available.



NOTE: (1) Connect to R_G for desired gain.

INA110

4

INSTRUMENTATION AMPLIFIERS

For Immediate Assistance, Contact Your Local Salesperson

SPECIFICATIONS

ELECTRICAL

At +25°C, $\pm V_{CC} = 15VDC$, and $R_L = 2k\Omega$, unless otherwise specified.

| PARAMETER | CONDITIONS | INA110AG | | | INA110BG, SG | | | INA110KP, KU | | | UNITS |
|---|---------------------------------------|----------|-------------------------|-----------------|----------------------------------|---------------|-----------------|--------------|-----------------|------------------|----------------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| GAIN | | | | | | | | | | | |
| Range of Gain | | 1 | | 800 | * | | * | * | | * | V/V |
| Gain Equation ⁽¹⁾ | | | * | | $G = 1 + [40k/(R_G + 50\Omega)]$ | | | | * | | V/V |
| Gain Error, DC: G = 1 | | | 0.002 | 0.04 | | * | 0.02 | | * | * | % |
| G = 10 | | | 0.01 | 0.1 | | 0.005 | 0.05 | | * | * | % |
| G = 100 | | | 0.02 | 0.2 | | 0.01 | 0.1 | | * | * | % |
| G = 200 | | | 0.04 | 0.4 | | 0.02 | 0.2 | | * | * | % |
| G = 500 | | | 0.1 | 1 | | 0.05 | 0.5 | | * | * | % |
| Gain Temp. Coefficient: G = 1 | | | ±3 | ±20 | | * | ±10 | | * | * | ppm/°C |
| G = 10 | | | ±4 | ±20 | | ±2 | ±10 | | * | * | ppm/°C |
| G = 100 | | | ±6 | ±40 | | ±3 | ±20 | | * | * | ppm/°C |
| G = 200 | | | ±10 | ±60 | | ±5 | ±30 | | * | * | ppm/°C |
| G = 500 | | | ±25 | ±100 | | ±10 | ±50 | | * | * | ppm/°C |
| Nonlinearity, DC: G = 1 | | | ±0.001 | ±0.01 | | ±0.0005 | ±0.005 | | * | * | % of FS |
| G = 10 | | | ±0.002 | ±0.01 | | ±0.001 | ±0.005 | | * | * | % of FS |
| G = 100 | | | ±0.004 | ±0.02 | | ±0.002 | ±0.01 | | * | * | % of FS |
| G = 200 | | | ±0.006 | ±0.02 | | ±0.003 | ±0.01 | | * | * | % of FS |
| G = 500 | | | ±0.01 | ±0.04 | | ±0.005 | ±0.02 | | * | * | % of FS |
| OUTPUT | | | | | | | | | | | |
| Voltage, $R_L = 2k\Omega$ | Over Temperature | ±10 | ±12.7 | | * | * | | * | * | | V |
| Current | Over Temperature | ±5 | ±25 | | * | * | | * | * | | mA |
| Short-Circuit Current | | | ±25 | | | * | | | * | | mA |
| Capacitive Load | Stability | | 5000 | | | * | | | * | | pF |
| INPUT OFFSET VOLTAGE⁽²⁾ | | | | | | | | | | | |
| Initial Offset: G, P | | | ±(100 + 1000/G) | ±(500 + 5000/G) | | ±(50 + 600/G) | ±(250 + 3000/G) | | * | * | μV |
| U | | | | | | | | | ±(200 + 2000/G) | ±(1000 + 5000/G) | μV |
| vs Temperature | | | ±(2 + 20/G) | ±(5 + 100/G) | | ±(1 + 10/G) | ±(2 + 50/G) | | * | * | μV/°C |
| vs Supply | $V_{CC} = \pm 6V$ to $\pm 18V$ | | ±(4 + 60/G) | ±(30 + 300/G) | | ±(2 + 30/G) | ±(10 + 180/G) | | * | * | μV/V |
| BIAS CURRENT | | | | | | | | | | | |
| Initial Bias Current | Each Input | | 20 | 100 | | 10 | 50 | | * | * | pA |
| Initial Offset Current | | | 2 | 50 | | 1 | 25 | | * | * | pA |
| Impedance: Differential | | | $5 \times 10^{12} 6$ | | | * | | | * | * | Ω pF |
| Common-Mode | | | $2 \times 10^{12} 1$ | | | * | | | * | * | Ω pF |
| VOLTAGE RANGE | | | | | | | | | | | |
| Range, Linear Response | V_{IN} Diff. = $0V^{(3)}$ | ±10 | ±12 | | | | | * | * | | V |
| CMR with $1k\Omega$ Source Imbalance: | | | | | | | | | | | |
| G = 1 | DC | 70 | 90 | | 80 | 100 | | * | * | | dB |
| G = 10 | DC | 87 | 104 | | 96 | 112 | | * | * | | dB |
| G = 100 | DC | 100 | 110 | | 106 | 116 | | * | * | | dB |
| G = 200 | DC | 100 | 110 | | 106 | 116 | | * | * | | dB |
| G = 500 | DC | 100 | 110 | | 106 | 116 | | * | * | | dB |
| INPUT NOISE⁽⁴⁾ | | | | | | | | | | | |
| Voltage, $f_O = 10kHz$ | | | 10 | | | * | | | * | | nV/\sqrt{Hz} |
| $f_B = 0.1Hz$ to $10Hz$ | | | 1 | | | * | | | * | | $\mu Vp-p$ |
| Current, $f_O = 10kHz$ | | | 1.8 | | | * | | | * | | fA/\sqrt{Hz} |
| OUTPUT NOISE⁽⁴⁾ | | | | | | | | | | | |
| Voltage, $f_O = 10kHz$ | | | 65 | | | * | | | * | | nV/\sqrt{Hz} |
| $f_B = 0.1Hz$ to $10Hz$ | | | 8 | | | * | | | * | | $\mu Vp-p$ |
| DYNAMIC RESPONSE | | | | | | | | | | | |
| Small Signal: G = 1 | -3dB | | 2.5 | | | * | | | * | | MHz |
| G = 10 | | | 2.5 | | | * | | | * | | MHz |
| G = 100 | | | 470 | | | * | | | * | | kHz |
| G = 200 | | | 240 | | | * | | | * | | kHz |
| G = 500 | | | 100 | | | * | | | * | | kHz |
| Full Power | $V_{OUT} = \pm 10V$, G = 2 to 100 | 190 | 270 | | * | * | | | * | * | kHz |
| Slew Rate | G = 2 to 100 | 12 | 17 | | * | * | | | * | * | V/μs |
| Settling Time: | | | | | | | | | | | |
| 0.1%, G = 1 | $V_O = 20V$ Step | | 4 | | | * | | | * | | μs |
| G = 10 | | | 2 | | | * | | | * | | μs |
| G = 100 | | | 3 | | | * | | | * | | μs |
| G = 200 | | | 5 | | | * | | | * | | μs |
| G = 500 | | | 11 | | | * | | | * | | μs |

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SPECIFICATIONS (CONT)

ELECTRICAL

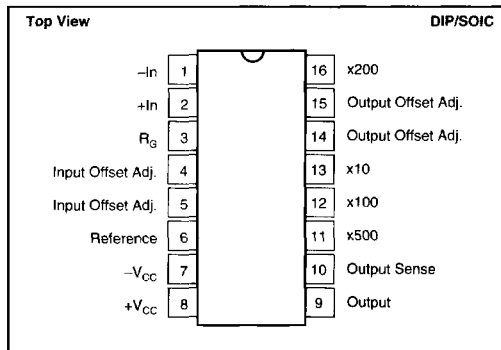
At +25°C, $\pm V_{CC}$ 15VDC, and $R_L = 2K\Omega$, unless otherwise specified.

| PARAMETER | CONDITIONS | INA110AG | | | INA110BG, SG | | | INA110KP, KU | | | UNITS |
|--------------------------------|------------------|----------|----------|-----------|--------------|-----|------|--------------|-----|-----|---------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| DYNAMIC RESPONSE (CONT) | | | | | | | | | | | |
| Settling Time: 0.01%, G = 1 | $V_O = 20V$ Step | | 5 | 12.5 | | * | * | | * | | μS |
| G = 10 | | | 3 | 7.5 | | * | * | | * | | μS |
| G = 100 | | | 4 | 7.5 | | * | * | | * | | μS |
| G = 200 | | | 7 | 12.5 | | * | * | | * | | μS |
| G = 500 | | | 16 | 25 | | * | * | | * | | μS |
| Recovery ⁽⁵⁾ | 50% Overdrive | | 1 | | | * | | | * | | μS |
| POWER SUPPLY | | | | | | | | | | | |
| Rated Voltage | $V_O = 0V$ | | ± 15 | | | * | * | | * | | V |
| Voltage Range | | ± 6 | | ± 18 | * | | * | * | * | | V |
| Quiescent Current | | | ± 3 | ± 4.5 | | * | * | * | * | | mA |
| TEMPERATURE RANGE | | | | | | | | | | | |
| Specification: A, B, K | | -25 | | +85 | * | | * | 0 | | +70 | °C |
| S | | | | | -55 | | +125 | | | | °C |
| Operation | | -55 | | +125 | * | | * | -25 | | +85 | °C |
| Storage | | -65 | | +150 | * | | * | -40 | | +85 | °C |
| θ_{JA} | | | 100 | | | * | | | * | | °C/W |

*: Same as INA110AG.

NOTES: (1) Gains other than 1, 10, 100, 200, and 500 can be set by adding an external resistor, R_G , between pin 3 and pins 11, 12 and 16. Gain accuracy is a function of R_G and the internal resistors which have a $\pm 20\%$ tolerance with 20ppm/°C drift. (2) Adjustable to zero. (3) For differential input voltage other than zero, see Typical Performance Curves. (4) $V_{NOISE RTI} = \sqrt{V_{N, INPUT}^2 + (V_{N, OUTPUT}/Gain)^2}$. (5) Time required for output to return from saturation to linear operation following the removal of an input overdrive voltage.

PIN CONFIGURATION



ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ABSOLUTE MAXIMUM RATINGS

| | |
|---|----------------------|
| Supply Voltage | $\pm 18V$ |
| Input Voltage Range | $\pm V_{CC}$ |
| Operating Temperature Range: G | -55°C to +125°C |
| P, U | -25°C to +85°C |
| Storage Temperature Range: G | -65°C to +150°C |
| P, U | -40°C to +85°C |
| Lead Temperature (soldering, 10s): G, P | +300°C |
| (soldering, 3s): U | +260°C |
| Output Short Circuit Duration | Continuous to Common |

PACKAGE/ORDERING INFORMATION

| PRODUCT | PACKAGE | PACKAGE DRAWING NUMBER ⁽¹⁾ | TEMPERATURE RANGE |
|----------|--------------------|---------------------------------------|-------------------|
| INA110AG | 16-Pin Ceramic DIP | 109 | -25°C to +85°C |
| INA110BG | 16-Pin Ceramic DIP | 109 | -25°C to +85°C |
| INA110SG | 16-Pin Ceramic DIP | 109 | -55°C to +125°C |
| INA110KP | 16-Pin Plastic DIP | 180 | 0°C to +70°C |
| INA110KU | SOL-16 SOIC | 211 | 0°C to +70°C |

NOTE: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book.

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